

**Vishay Siliconix** 

# P-Channel 1.8 V (G-S) MOSFET

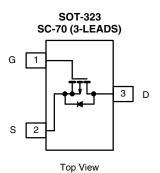
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)		
- 8	0.280 at V <sub>GS</sub> = - 4.5 V	- 0.92		
	0.380 at V <sub>GS</sub> = - 2.5 V	- 0.79		
	0.530 at V <sub>GS</sub> = - 1.8 V	- 0.67		

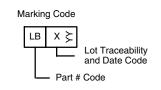
#### **FEATURES**

- TrenchFET<sup>®</sup> Power MOSFET: 1.8 V
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT HALOGEN FREE





Ordering Information: Si1305DL-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	$(1_A = 25^{\circ} \text{ G}, \text{ united})$	ess otherwise	noted)			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 8		V	
Gate-Source Voltage		V <sub>GS</sub>	± 8			
	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 0.92	- 0.86	۸	
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T <sub>A</sub> = 70 °C		- 0.74	- 0.69		
Pulsed Drain Current		I <sub>DM</sub>	- 3		A	
Continuous Diode Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 0,28	- 0.24		
	T <sub>A</sub> = 25 °C	P_	0.34	0.29	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	– P <sub>D</sub>	0.22	0.19		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mandanana kanadan ka Anakianda	t ≤ 5 s	– R <sub>thJA</sub>	315	375	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		360	430	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	285	340	

Note:

a. Surface mounted on 1" x 1" FR4 board.

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<b>SPECIFICATIONS</b> $(T_J = 25^{\circ})$	-						
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$				V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V$ , $V_{GS} = \pm 8 V$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -8 V, V_{GS} = 0 V$	- 1		- 1		
		$V_{DS}$ = - 8 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			- 5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V$ , $V_{GS} = -4.5 V$	- 3			А	
	R <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -1 \text{ A}$		0.230	0.280	Ω	
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS}$ = - 2.5 V, I <sub>D</sub> = - 0.5 A		0.315	0.380		
		$V_{GS} = -1.8 \text{ V}, \text{ I}_{D} = -0.3 \text{ A}$		0.440	0.530		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = -5 V, I_{D} = -1 A$		3.5		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 0.3 A, V <sub>GS</sub> = 0 V			- 1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			2.6	4		
Gate-Source Charge	Q <sub>gs</sub>	$Q_{gs}$ $V_{DS} = -4 V, V_{GS} = -4.5 V, I_{D} = -1 A$		0.6		nC	
Gate-Drain Charge	Q <sub>gd</sub>			0.5			
Turn-On Delay Time	t <sub>d(on)</sub>			8	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 4 V, $R_L$ = 4 $\Omega$		55	80		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 1 A, $\text{V}_\text{GEN}$ = - 4.5 V, $\text{R}_\text{g}$ = 6 $\Omega$		17	25	ns	
Fall Time	t <sub>f</sub>			12	20		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1 A, dl/dt = 100 A/μs		27	45		

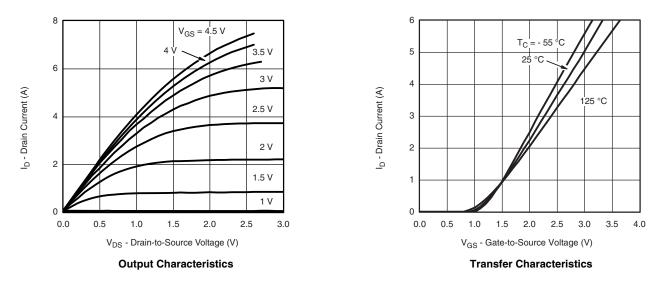
Notes:

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



For technical questions, contact: pmostechsupport@vishay.com

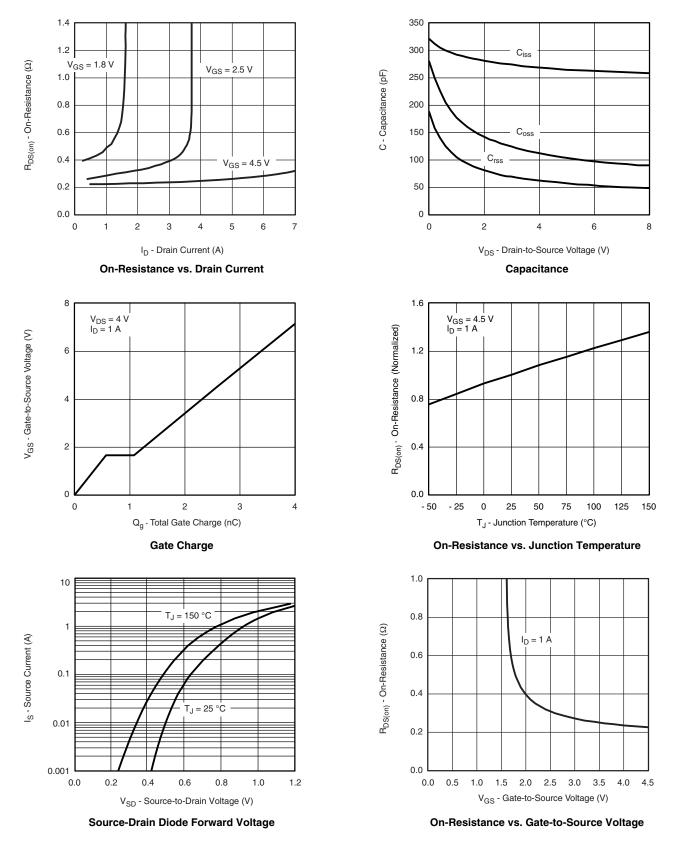
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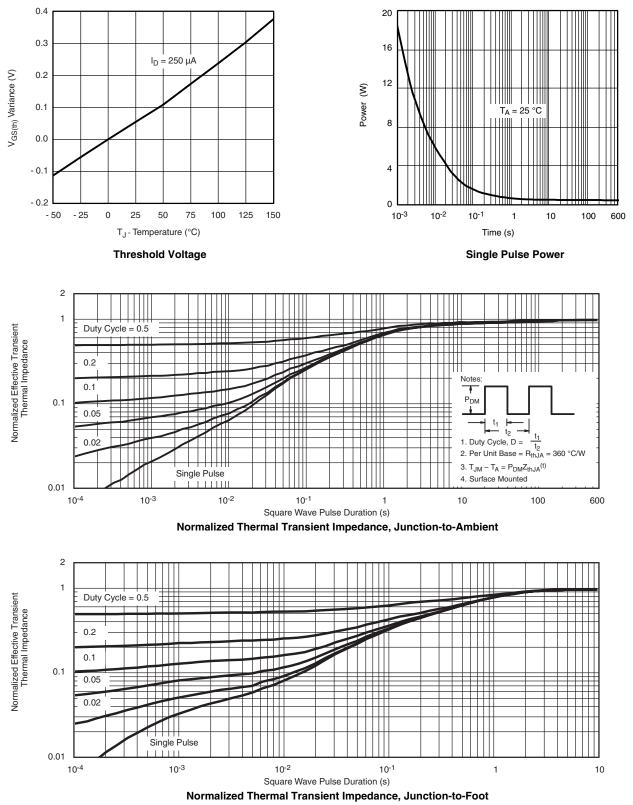
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### Si1305DL



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